

Application Data Sheet

Application Information

Application Type:: Regular
Subject Matter:: Utility
Suggested Group Art Unit:: Not Yet Assigned
CD-ROM or CD-R?:: None
Sequence submission?:: None
Computer Readable Form (CRF)?:: No
Title:: SEMICONDUCTOR MEMORY DEVICE
AND METHOD FOR PROGRAMMING AND
ERASING A MEMORY CELL
Attorney Docket Number:: 559502000500
Request for Early Publication?:: No
Request for Non-Publication?:: No
Total Drawing Sheets:: 15
Small Entity?:: No
Petition included?:: No
Secrecy Order in Parent Appl.?:: No

Applicant Information

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
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Family Name:: MATSUOKA
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City of mailing address:: Tenri
State or Province of mailing address:: Nara
Country of mailing address:: Japan

Postal or Zip Code of mailing address:: 632-0004

Correspondence Information

Correspondence Customer Number:: 25226

Representative Information

Representative Customer Number:: 25226

Foreign Priority Information

Country::	Application number::	FilingDate::	Priority Claimed::
Japan	2002-353053	12/04/02	Yes
Japan	2003-018645	01/28/03	Yes

Assignee Information

Assignee name:: SHARP KABUSHIKI KAISHA

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